NSN 5961-01-383-8149

Transistor - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

10.15 millimeters

Terminal Length:

3.8 millimeters

Overall Height:

1.8 millimeters

Overall Width:

10.15 millimeters

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, collector-to-base, emitter open and 12.0 breakdown voltage, collector-to-emitter, base open and 1.5 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

65.00 milliamperes source cutoff current and 0.10 microamperes zero-gate-voltage source current preset and 1.00 microamperes

zero-gate-voltage source current major

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-emitter absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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